TOSHIBA Fast Recovery Diode Silicon Diffused Type

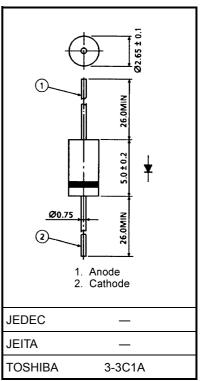
TFR2N, TFR2T

Strobo Flasher Applications (Fast Recovery)

- Average forward current: $I_F (AV) = 0.5 A$
- Repetitive peak reverse voltage: $V_{RRM} = 1000, 1500 V$
- Reverse-Recovery Time: $t_{rr} = 4 \mu s$

Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|-------------------------------------------------------|-------|--------------------|---------|------------------|
| Repetitive peak reverse voltage | TFR2N | V _{RRM} | 1000 | V |
| | TFR2T | | 1500 | v |
| Average forward current | | I _{F(AV)} | 0.5 | А |
| I ² t limit value (t = 1~10 ms) | | l ² t | 2 | A ² s |
| Peak one cycle surge forward current (non-repetitive) | | I _{FSM} | 20 | А |
| Junction temperature | | Тj | -40~125 | °C |
| Storage temperature range | | T _{stg} | -40~125 | °C |

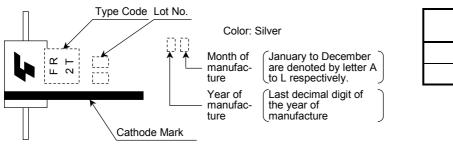


Weight: 0.3 g (typ.)

Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Max | Unit |
|---------------------------------|------------------|-----------------------------------------------|-----|-----|------|
| Peak forward voltage | V_{FM} | I _{FM} = 0.5 A | _ | 1.5 | V |
| Repetitive peak reverse current | I _{RRM} | V _{RRM} = Rated | _ | 10 | μA |
| Reverse recovery time | t _{rr} | I _F = 20 mA, I _R = 1 mA | | 4 | μS |

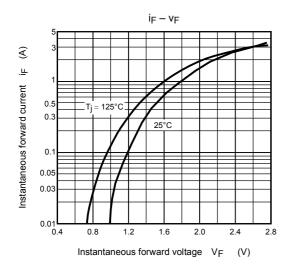
Marking

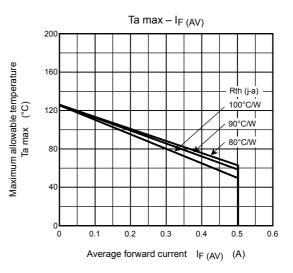


| Code | Туре |
|------|-------|
| FR2N | TFR2N |
| FR2T | TFR2T |

Unit: mm

TOSHIBA

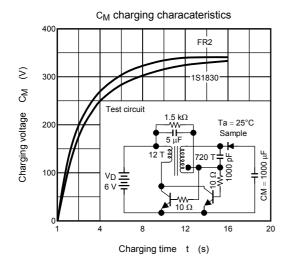




Thermal resistance characteristics 100 Thermal resistance Rth (j-a) (°C/W) Leadwire length 90 80 1 1/2 70 1/4 60 0 2 3 4 5 Printed circuit board area (cm²) (copper 0.5 t)

Surge forward current (non-repetitive)





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